

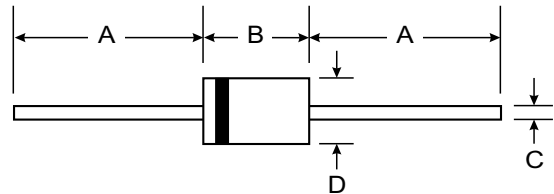
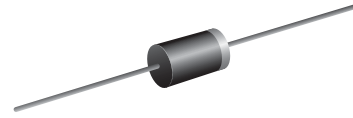
**VOLTAGE RANGE: 100 - 200V**  
**CURRENT: 1.6 A**

### Features

- Low leakage
- Low forward voltage drop
- High current capability
- Easily cleaned with alcohol, Isopropanol and similar solvents

### Mechanical Data

- Case: DO-201AD, molded plastic
- Terminals: Axial lead, solderable per MIL-STD202, method 208
- Polarity: Color band denotes cathode
- Weight: 0.041 ounces, 1.15 grams
- Mounting position: Any



| DO-201AD             |       |      |
|----------------------|-------|------|
| Dim                  | Min   | Max  |
| A                    | 25.40 | —    |
| B                    | 7.20  | 9.50 |
| C                    | 1.20  | 1.30 |
| D                    | 4.80  | 5.30 |
| All Dimensions in mm |       |      |

### Maximum Ratings and Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

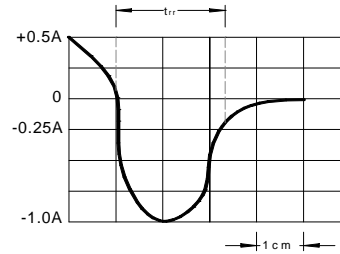
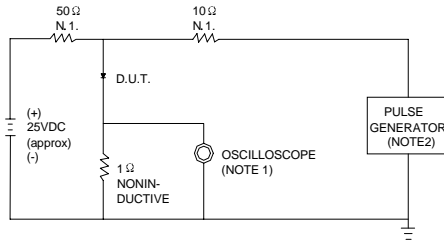
| Characteristic  | Symbol             | 31DF1            | 31DF2 | Unit |
|---|--------------------|------------------|-------|------|
| Maximum recurrent peak reverse voltage  | V <sub>RRM</sub>   | 100              | 200   | V    |
| Maximum RMS voltage   | V <sub>RMS</sub>   | 70               | 140   | V    |
| Maximum DC blocking voltage   | V <sub>DC</sub>    | 100              | 200   | V    |
| Maximum average forward rectified current<br>9.5mm lead length, @T <sub>A</sub> =75°C                         | I <sub>F(AV)</sub> | 1.6              |       | A    |
| Peak forward surge current<br>10ms single half-sine-wave<br>superimposed on rated load @T <sub>J</sub> =125°C | I <sub>FSM</sub>   | 125.0            |       | A    |
| Maximum instantaneous forward voltage<br>@ I <sub>F</sub> =1.6A   | V <sub>F</sub>     | 0.98             |       | V    |
| Maximum reverse current @T <sub>A</sub> =25°C<br>at rated DC blocking voltage @T <sub>A</sub> =100°C          | I <sub>R</sub>     | 5.0              | 50.0  | μA   |
| Maximum reverse recovery time (Note1)   | t <sub>rr</sub>    | 30               |       | ns   |
| Typical junction capacitance (Note2)  | C <sub>J</sub>     | 90               |       | pF   |
| Typical thermal resistance (Note3)  | R <sub>θJA</sub>   | 34               |       | °C/W |
| Operating junction temperature range  | T <sub>J</sub>     | - 55 ----- + 150 |       | °C   |
| Storage temperature range   | T <sub>STG</sub>   | - 55 ----- + 150 |       | °C   |

NOTE: 1. Measured with I<sub>F</sub>=0.5A, I<sub>R</sub>=1A, I<sub>rr</sub>=0.25A.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

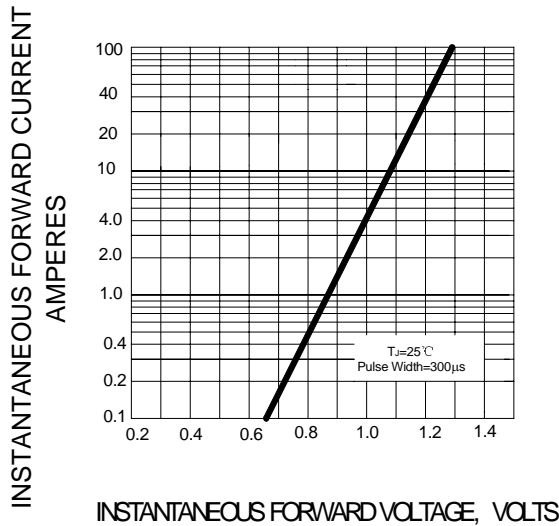
**FIG.1 – TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC**



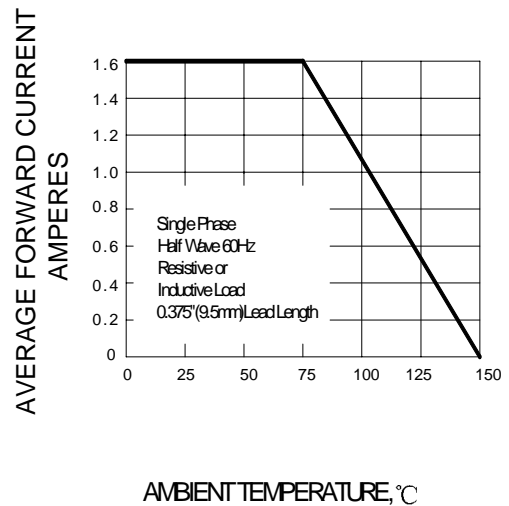
SET TIMEBASE FOR 10 ns/cm

NOTES: 1. RISE TIME = 7ns MAX INPUT IMPEDANCE = 1M $\Omega$ , 22pF.  
2. RISE TIME = 10ns MAX SOURCE IMPEDANCE = 50  $\Omega$ .

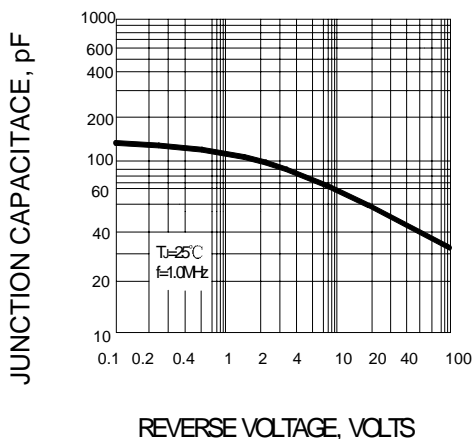
**FIG.2 – TYPICAL FORWARD CHARACTERISTIC**



**FIG.3 – FORWARD DERATING CURVE**



**FIG.4 – TYPICAL JUNCTION CAPACITANCE**



**FIG.5 – PEAK FORWARD SURGE CURRENT**

